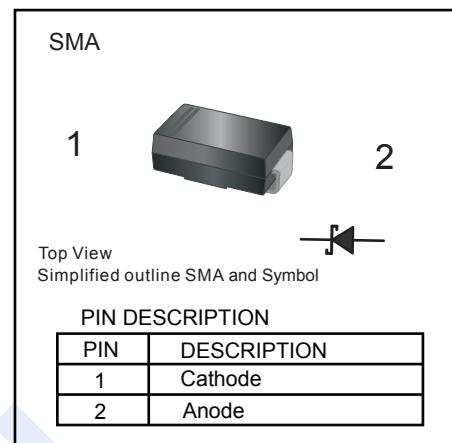


## Schottky Barrier Rectifier

### SS34L

#### ■ Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



#### ■ Maximum Ratings and Electrical characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbol	SS34L	Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	40	V
Maximum RMS voltage	$V_{RMS}$	28	
Maximum DC Blocking Voltage	$V_{DC}$	40	
Maximum Instantaneous Forward Voltage at 3 A	$V_F$	0.45	
Maximum Average Forward Rectified Current at $T_c = 100^\circ\text{C}$	$I_{F(AV)}$	3	A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	$I_{FSM}$	80	
Maximum DC Reverse Current $T_a=25^\circ\text{C}$ at Rated DC Blocking Voltage $T_a=100^\circ\text{C}$	$I_R$	0.3 5	mA
Typical Junction Capacitance *1	$C_j$	450	pF
Typical thermal resistance *2	$R_{thJA}$	60	°C/W
Junction Temperature	$T_j$	150	°C
Storage Temperature	$T_{stg}$	-55 ~ +150	

\* 1 Measured at 1MHz and applied reverse voltage of 4V D.C

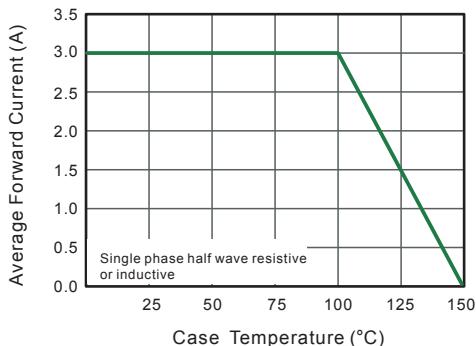
\* 2 P.C.B. mounted with 2" × 2" (5×5 cm) copper pad areas.

## Schottky Barrier Rectifier

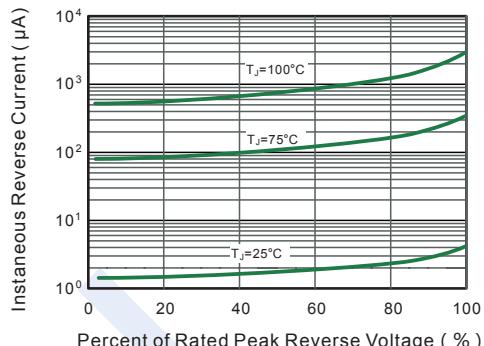
**SS34L**

### ■ Typical Characteristics

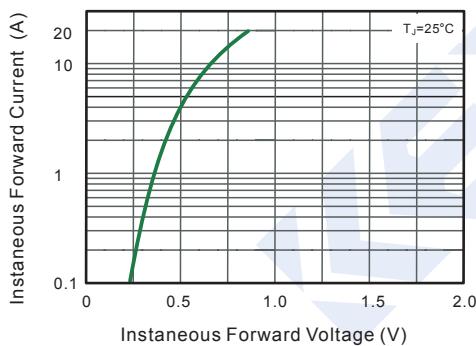
**Fig.1 Forward Current Derating Curve**



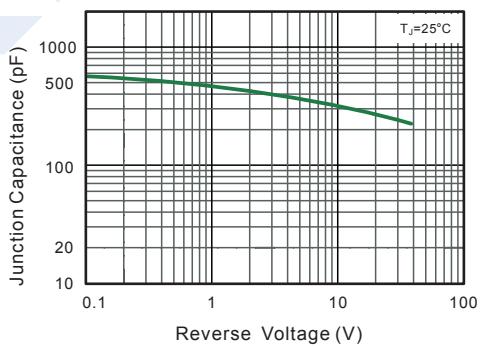
**Fig.2 Typical Reverse Characteristics**



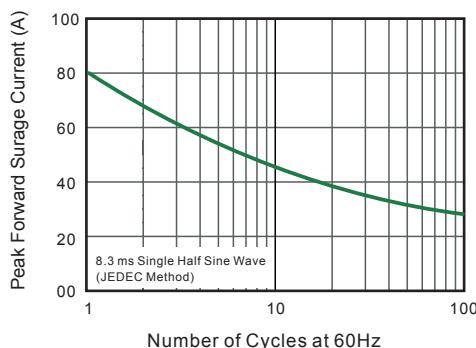
**Fig.3 Typical Forward Characteristic**



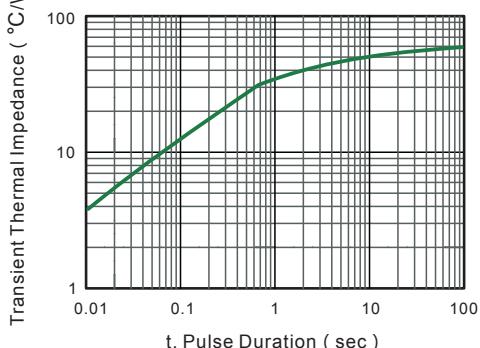
**Fig.4 Typical Junction Capacitance**



**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.5- Typical Transient Thermal Impedance**



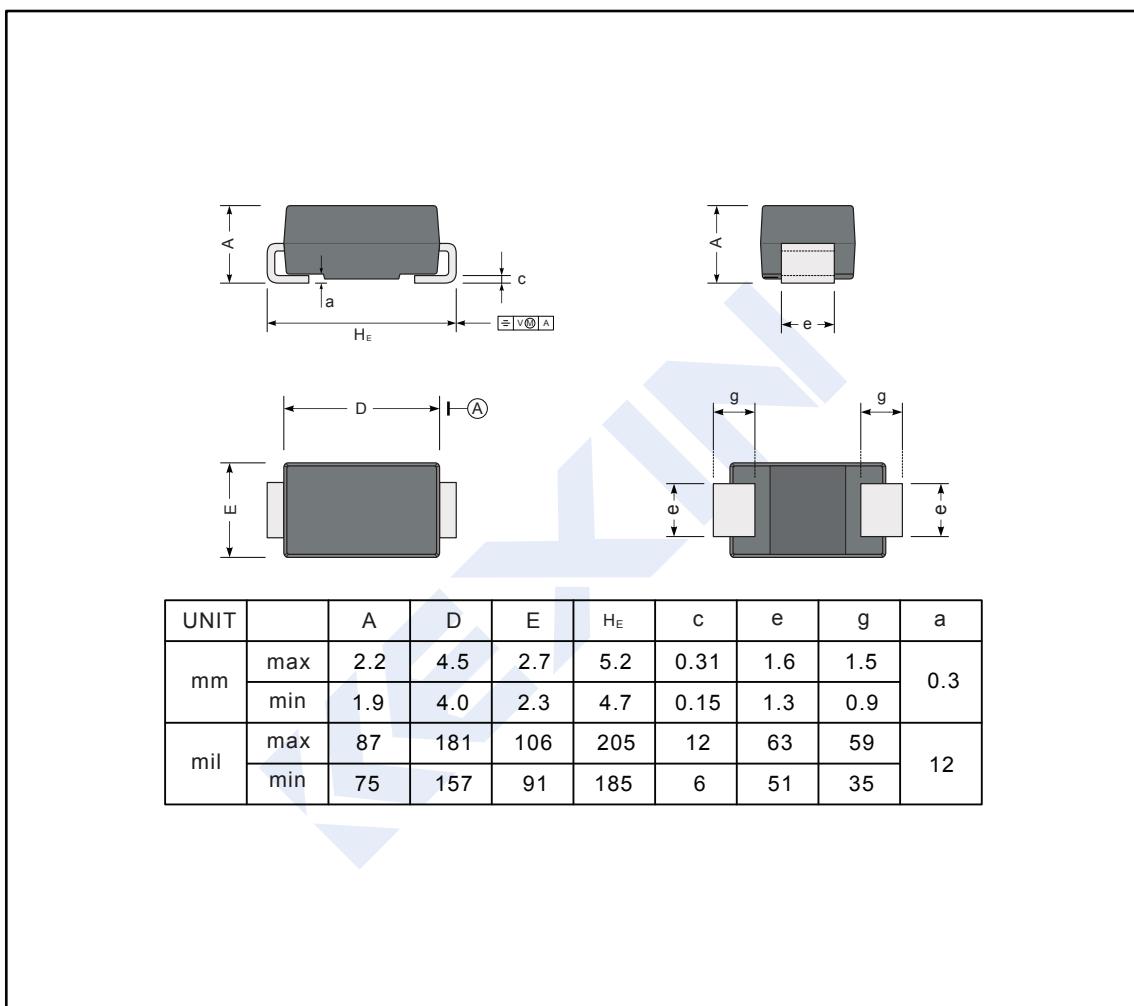
## Schottky Barrier Rectifier

### SS34L

#### ■ Package Outline Dimensions

Plastic surface mounted package; 2 leads

SMA



#### ■ The recommended mounting pad size

